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Embedded - System On Chip (SoC): The Heart of Modern Embedded Systems

Embedded - System On Chip (SoC) refers to an integrated circuit that consolidates all the essential components of a computer system into a single chip. This includes a microprocessor, memory, and other peripherals, all packed into one compact and efficient package. SoCs are designed to provide a complete computing solution, optimizing both space and power consumption, making them ideal for a wide range of embedded applications.

What are Embedded - System On Chip (SoC)?

System On Chip (SoC) integrates multiple functions of a computer or electronic system onto a single chip. Unlike traditional multi-chip solutions, SoCs combine a central

Details

| | |
|-------------------------|---|
| Product Status | Obsolete |
| Architecture | MCU, FPGA |
| Core Processor | ARM® Cortex®-M3 |
| Flash Size | 512KB |
| RAM Size | 64KB |
| Peripherals | DDR, PCIe, SERDES |
| Connectivity | CANbus, Ethernet, I ² C, SPI, UART/USART, USB |
| Speed | 166MHz |
| Primary Attributes | FPGA - 100K Logic Modules |
| Operating Temperature | 0°C ~ 85°C (TJ) |
| Package / Case | 1152-BBGA, FCBGA |
| Supplier Device Package | 1152-FCBGA (35x35) |
| Purchase URL | https://www.e-xfl.com/product-detail/microsemi/m2s100-fcg1152 |

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2.2 References

The following documents are recommended references:

- *PB0121: IGLOO2 Product Brief*
- *DS0124: IGLOO2 Pin Descriptions*
- *PB0115: SmartFusion2 SoC FPGA Product Brief*
- *DS0115: SmartFusion2 Pin Descriptions*

All product documentation for IGLOO2 and SmartFusion2 is available at:

<http://www.microsemi.com/products/fpga-soc/fpga/igloo2-fpga>

<http://www.microsemi.com/products/fpga-soc/soc-fpga/smartfusion2#overview>

2.3 Electrical Specifications

2.3.1 Operating Conditions

The following table lists the stress limits. Stress applied above the specified limit may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Absolute maximum ratings are stress ratings only; functional operation of the device at these or any other conditions beyond those listed under the recommended operating conditions specified in the following table are not implied.

Table 3 • Absolute Maximum Ratings

| Parameter | Symbol | Min | Max | Unit |
|--|-----------------------------|------|------|------|
| DC core supply voltage. Must always power this pin. | V_{DD} | -0.3 | 1.32 | V |
| Power supply for charge pumps (for normal operation and programming). Must always power this pin. | V_{PP} | -0.3 | 3.63 | V |
| Analog power pad for MDDR PLL | MSS_MDDR_PLL_VDDA | -0.3 | 3.63 | V |
| Analog power pad for MDDR PLL | HPMS_MDDR_PLL_VDDA | -0.3 | 3.63 | V |
| Analog power pad for FDDR PLL | FDDR_PLL_VDDA | -0.3 | 3.63 | V |
| Analog power pad for MDDR PLL | PLL0_PLL1_MSS_MDDR_VDDA | -0.3 | 3.63 | V |
| Analog power pad for MDDR PLL | PLL0_PLL1_HPMS_MDDR_VDDA | -0.3 | 3.63 | V |
| Analog power pad for PLL0-5 | CCC_XX[01]_PLL_VDDA | -0.3 | 3.63 | V |
| High supply voltage for PLL SerDes[01] | SERDES_[01]_PLL_VDDA | -0.3 | 3.63 | V |
| Analog power for SerDes[01] PLL lane0 to lane3. This is a 2.5 V SerDes internal PLL supply. | SERDES_[01]_L[0123]_VDDAPLL | -0.3 | 2.75 | V |
| TX/RX analog I/O voltage. Low voltage power for the lanes of SerDesIF0. This is a 1.2 V SerDes PMA supply. | SERDES_[01]_L[0123]_VDDAIO | -0.3 | 1.32 | V |
| PCIe/PCS power supply | SERDES_[01]_VDD | -0.3 | 1.32 | V |
| DC FPGA I/O buffer supply voltage for MSIO I/O bank | V_{DDIx} | -0.3 | 3.63 | V |
| DC FPGA I/O buffer supply voltage for MSIOD/DDRIO I/O banks | V_{DDIx} | -0.3 | 2.75 | V |
| I/O Input voltage for MSIO I/O bank | V_I | -0.3 | 3.63 | V |
| I/O Input voltage for MSIOD/DDRIO I/O bank | V_I | -0.3 | 2.75 | V |
| Analog sense circuit supply of embedded nonvolatile memory (eNVM). Must be shorted to V_{PP} . | V_{PPNVM} | -0.3 | 3.63 | V |
| Storage temperature ¹ | T_{STG} | -65 | 150 | °C |
| Junction temperature | T_J | -55 | 135 | °C |

1. For flash programming and retention maximum limits, see Table 5, page 7. For recommended operating conditions, see Table 4, page 6.

Table 4 • Recommended Operating Conditions

| Parameter | Symbol | Min | Typ | Max | Unit | Conditions |
|---|---------------------------------|-------|-----|-------|------|-------------|
| Operating junction temperature | T_J | 0 | 25 | 85 | °C | Commercial |
| | | -40 | 25 | 100 | °C | Industrial |
| Programming junction temperatures ¹ | T_J | 0 | 25 | 85 | °C | Commercial |
| | | -40 | 25 | 100 | °C | Industrial |
| DC core supply voltage. Must always power this pin. | V_{DD} | 1.14 | 1.2 | 1.26 | V | |
| Power supply for charge pumps (for normal operation and programming) for the 005, 010, 025, 050, 060 devices | V_{PP} | 2.375 | 2.5 | 2.625 | V | 2.5 V range |
| | | 3.15 | 3.3 | 3.45 | V | 3.3 V range |
| Power supply for charge pumps (for normal operation and programming) for the 090 and 150 devices | V_{PP} | 3.15 | 3.3 | 3.45 | V | 3.3 V range |
| Analog power pad for MDDR PLL | MSS_MDDR_PLL_VDDA | 2.375 | 2.5 | 2.625 | V | 2.5 V range |
| | | 3.15 | 3.3 | 3.45 | V | 3.3 V range |
| Analog power pad for MDDR PLL | HPMS_MDDR_PLL_VDDA | 2.375 | 2.5 | 2.625 | V | 2.5 V range |
| | | 3.15 | 3.3 | 3.45 | V | 3.3 V range |
| Analog power pad for FDDR PLL | FDDR_PLL_VDDA | 2.375 | 2.5 | 2.625 | V | 2.5 V range |
| | | 3.15 | 3.3 | 3.45 | V | 3.3 V range |
| Analog power pad for MDDR PLL | PLL0_PLL1_MSS_MDDR_V DDA | 2.375 | 2.5 | 2.625 | V | 2.5 V range |
| | | 3.15 | 3.3 | 3.45 | V | 3.3 V range |
| Analog power pad for MDDR PLL | PLL0_PLL1_HPMS_MDDR_ VDDA | 2.375 | 2.5 | 2.625 | V | 2.5 V range |
| | | 3.15 | 3.3 | 3.45 | V | 3.3 V range |
| Analog power pad for PLL0 to PLL5 | CCC_XX[01]_PLL_VDDA | 2.375 | 2.5 | 2.625 | V | 2.5 V range |
| | | 3.15 | 3.3 | 3.45 | V | 3.3 V range |
| High supply voltage for PLL SerDes[01] | SERDES_[01]_PLL_VDDA | 2.375 | 2.5 | 2.625 | V | 2.5 V range |
| | | 3.15 | 3.3 | 3.45 | V | 3.3 V range |
| Analog power for SerDes[01] PLL Lane 0 to Lane 3. This is a 2.5 V SerDes internal PLL supply. | SERDES_[01]_L[0123]_VD DAPLL | 2.375 | 2.5 | 2.625 | V | |
| TX/RX analog I/O voltage. Low voltage power for the lanes of SerDesIF0. This is a 1.2 V SerDes PMA supply. | SERDES_[01]_L[0123]_VD DAIO | 1.14 | 1.2 | 1.26 | V | |
| PCIe/PCS power supply | SERDES_[01]_VDD | 1.14 | 1.2 | 1.26 | V | |
| 1.2 V DC supply voltage | V_{DDix} | 1.14 | 1.2 | 1.26 | V | |
| 1.5 V DC supply voltage | V_{DDix} | 1.425 | 1.5 | 1.575 | V | |
| 1.8 V DC supply voltage | V_{DDix} | 1.71 | 1.8 | 1.89 | V | |
| 2.5 V DC supply voltage | V_{DDix} | 2.375 | 2.5 | 2.625 | V | |

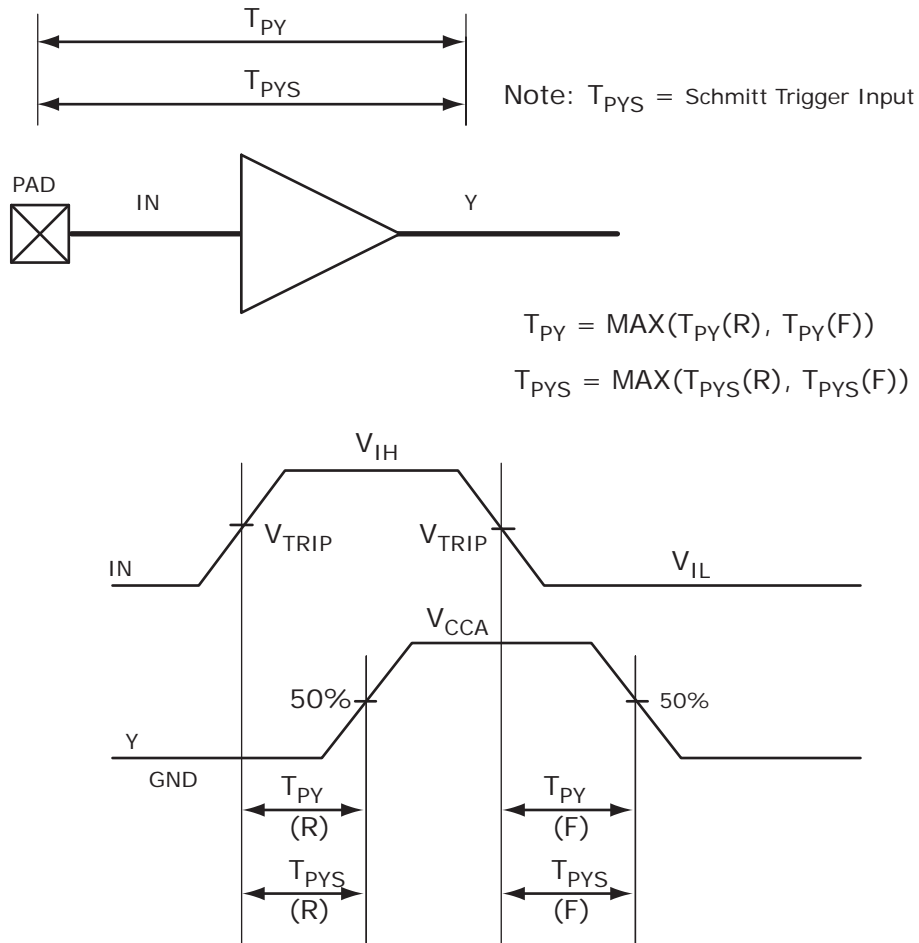
2.3.5 User I/O Characteristics

There are three types of I/Os supported in the IGLOO2 FPGA and SmartFusion2 SoC FPGA families: MSIO, MSIOD, and DDRIO I/O banks. The I/O standards supported by the different I/O banks is described in the I/Os section of the *UG0445: IGLOO2 FPGA and SmartFusion2 SoC FPGA Fabric User Guide*.

2.3.5.1 Input Buffer and AC Loading

The following figure shows the input buffer and AC loading.

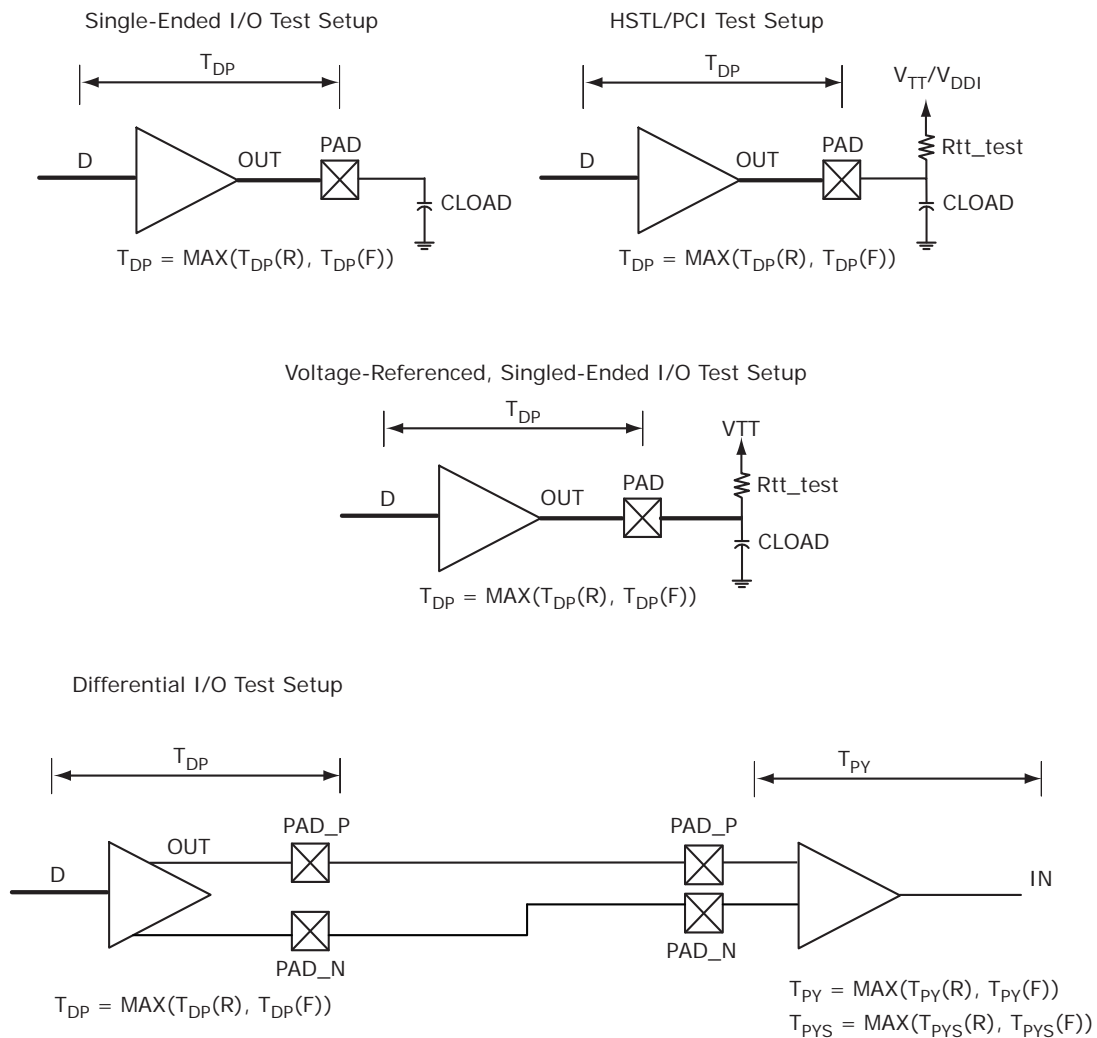
Figure 3 • Input Buffer AC Loading



2.3.5.2 Output Buffer and AC Loading

The following figure shows the output buffer and AC loading.

Figure 4 • Output Buffer AC Loading



2.3.5.5 Detailed I/O Characteristics

Table 24 • Input Capacitance, Leakage Current, and Ramp Time

| Symbol | Description | Maximum | Unit | Conditions |
|---------------------------|--|---------|---------|--------------------------------|
| C_{IN} | Input capacitance | 10 | pF | |
| I_{IL} (dc) | Input current low (Applicable to HSTL/SSTL inputs only) | 400 | μ A | $V_{DDI} = 2.5$ V |
| | | 500 | μ A | $V_{DDI} = 1.8$ V |
| | | 600 | μ A | $V_{DDI} = 1.5$ V ¹ |
| | Input current low (Applicable to all other digital inputs) | 10 | μ A | |
| I_{IH} (dc) | Input current high (Applicable to HSTL/SSTL inputs only) | 400 | μ A | $V_{DDI} = 2.5$ V |
| | | 500 | μ A | $V_{DDI} = 1.8$ V |
| | | 600 | μ A | $V_{DDI} = 1.5$ V ¹ |
| | Input current high (Applicable to all other digital inputs) | 10 | μ A | |
| T_{RAMPIN} ² | Input ramp time (Applicable to all digital inputs) | 50 | ns | |

1. Applicable when I/O pair is programmed with an HSTL/SSTL I/O type on IOP and an un-terminated I/O type (LVCMOS, for example) on ION pad.
2. Voltage ramp must be monotonic.

The following table lists the minimum and maximum I/O weak pull-up/pull-down resistance values of DDRIO I/O bank at V_{OH}/V_{OL} Level.

Table 25 • I/O Weak Pull-up/Pull-down Resistances for DDRIO I/O Bank

| V_{DDI} Domain | R(WEAK PULL-UP) at V_{OH} (Ω) | | R(WEAK PULL-DOWN) at V_{OL} (Ω) | |
|-----------------------|--|-------|--|-------|
| | Min | Max | Min | Max |
| 2.5 V ^{1, 2} | 10K | 17.8K | 9.98K | 18K |
| 1.8 V ^{1, 2} | 10.3K | 19.1K | 10.3K | 19.5K |
| 1.5 V ^{1, 2} | 10.6K | 20.2K | 10.6K | 21.1K |
| 1.2 V ^{1, 2} | 11.1K | 22.7K | 11.2K | 24.6K |

1. $R(\text{WEAK PULL-DOWN}) = (V_{OLspec})/I(\text{WEAK PULL-DOWN MAX})$.
2. $R(\text{WEAK PULL-UP}) = (V_{DDImax} - V_{OHspec})/I(\text{WEAK PULL-UP MIN})$.

Table 57 • LVCMOS 1.8 V Transmitter Characteristics for DDRIO I/O Bank with Fixed Code (Output and Tristate Buffers)

| Output Drive Selection | Slew Control | T _{DP} | | T _{ZL} | | T _{ZH} | | T _{HZ} ¹ | | T _{LZ} ¹ | | Unit |
|------------------------|--------------|-----------------|-------|-----------------|-------|-----------------|-------|------------------------------|-------|------------------------------|-------|------|
| | | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| 2 mA | Slow | 4.234 | 4.981 | 3.646 | 4.29 | 4.245 | 4.995 | 4.908 | 5.774 | 4.434 | 5.216 | ns |
| | Medium | 3.824 | 4.498 | 3.282 | 3.861 | 3.834 | 4.511 | 4.625 | 5.441 | 4.116 | 4.843 | ns |
| | Medium fast | 3.627 | 4.267 | 3.111 | 3.66 | 3.637 | 4.279 | 4.481 | 5.272 | 3.984 | 4.687 | ns |
| | Fast | 3.605 | 4.241 | 3.097 | 3.644 | 3.615 | 4.253 | 4.472 | 5.262 | 3.973 | 4.674 | ns |
| 4 mA | Slow | 3.923 | 4.615 | 3.314 | 3.9 | 3.918 | 4.61 | 5.403 | 6.356 | 4.894 | 5.757 | ns |
| | Medium | 3.518 | 4.138 | 2.961 | 3.484 | 3.515 | 4.135 | 5.121 | 6.025 | 4.561 | 5.366 | ns |
| | Medium fast | 3.321 | 3.907 | 2.783 | 3.275 | 3.317 | 3.903 | 4.966 | 5.843 | 4.426 | 5.206 | ns |
| | Fast | 3.301 | 3.883 | 2.77 | 3.259 | 3.296 | 3.878 | 4.957 | 5.831 | 4.417 | 5.196 | ns |
| 6 mA | Slow | 3.71 | 4.364 | 3.104 | 3.652 | 3.702 | 4.355 | 5.62 | 6.612 | 5.08 | 5.977 | ns |
| | Medium | 3.333 | 3.921 | 2.779 | 3.27 | 3.325 | 3.913 | 5.346 | 6.289 | 4.777 | 5.62 | ns |
| | Medium fast | 3.155 | 3.712 | 2.62 | 3.083 | 3.146 | 3.702 | 5.21 | 6.13 | 4.657 | 5.479 | ns |
| | Fast | 3.134 | 3.688 | 2.608 | 3.068 | 3.125 | 3.677 | 5.202 | 6.12 | 4.648 | 5.468 | ns |
| 8 mA | Slow | 3.619 | 4.258 | 3.007 | 3.538 | 3.607 | 4.244 | 5.815 | 6.841 | 5.249 | 6.175 | ns |
| | Medium | 3.246 | 3.819 | 2.686 | 3.16 | 3.236 | 3.807 | 5.542 | 6.52 | 4.936 | 5.807 | ns |
| | Medium fast | 3.066 | 3.607 | 2.525 | 2.971 | 3.054 | 3.593 | 5.405 | 6.359 | 4.811 | 5.66 | ns |
| | Fast | 3.046 | 3.584 | 2.513 | 2.957 | 3.034 | 3.57 | 5.401 | 6.353 | 4.803 | 5.651 | ns |
| 10 mA | Slow | 3.498 | 4.115 | 2.878 | 3.386 | 3.481 | 4.096 | 6.046 | 7.113 | 5.444 | 6.404 | ns |
| | Medium | 3.138 | 3.692 | 2.569 | 3.023 | 3.126 | 3.678 | 5.782 | 6.803 | 5.129 | 6.034 | ns |
| | Medium fast | 2.966 | 3.489 | 2.414 | 2.841 | 2.951 | 3.472 | 5.666 | 6.665 | 5.013 | 5.897 | ns |
| | Fast | 2.945 | 3.464 | 2.401 | 2.826 | 2.93 | 3.448 | 5.659 | 6.658 | 5.003 | 5.886 | ns |
| 12 mA | Slow | 3.417 | 4.02 | 2.807 | 3.303 | 3.401 | 4.002 | 6.083 | 7.156 | 5.464 | 6.428 | ns |
| | Medium | 3.076 | 3.618 | 2.519 | 2.964 | 3.063 | 3.604 | 5.828 | 6.856 | 5.176 | 6.089 | ns |
| | Medium fast | 2.913 | 3.427 | 2.376 | 2.795 | 2.898 | 3.41 | 5.725 | 6.736 | 5.072 | 5.966 | ns |
| | Fast | 2.894 | 3.405 | 2.362 | 2.78 | 2.879 | 3.388 | 5.715 | 6.724 | 5.064 | 5.957 | ns |
| 16 mA | Slow | 3.366 | 3.96 | 2.751 | 3.237 | 3.348 | 3.939 | 6.226 | 7.324 | 5.576 | 6.56 | ns |
| | Medium | 3.03 | 3.565 | 2.47 | 2.906 | 3.017 | 3.55 | 5.981 | 7.036 | 5.282 | 6.214 | ns |
| | Medium fast | 2.87 | 3.377 | 2.328 | 2.739 | 2.854 | 3.358 | 5.895 | 6.935 | 5.18 | 6.094 | ns |
| | Fast | 2.853 | 3.357 | 2.314 | 2.723 | 2.837 | 3.338 | 5.889 | 6.929 | 5.177 | 6.09 | ns |

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

Table 82 • LVCMOS 1.2 V Receiver Characteristics for MSIOD I/O Bank (Input Buffers)

| On-Die Termination (ODT) | T_{PY} | | T_{PYS} | | Unit |
|--------------------------|----------|-------|-----------|-------|------|
| | -1 | -Std | -1 | -Std | |
| None | 4.154 | 4.887 | 4.114 | 4.84 | ns |
| 50 | 6.918 | 8.139 | 6.806 | 8.008 | ns |
| 75 | 5.613 | 6.603 | 5.533 | 6.509 | ns |
| 150 | 4.716 | 5.549 | 4.657 | 5.479 | ns |

Table 83 • LVCMOS 1.2 V Transmitter Characteristics for DDRIO I/O Bank (Output and Tristate Buffers)

| Output Drive Selection | Slew Control | T_{DP} | | T_{ZL} | | T_{ZH} | | T_{HZ}^1 | | T_{LZ}^1 | | Unit |
|------------------------|--------------|----------|-------|----------|-------|----------|-------|------------|-------|------------|-------|------|
| | | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| 2 mA | Slow | 6.713 | 7.897 | 5.362 | 6.308 | 6.723 | 7.909 | 7.233 | 8.51 | 6.375 | 7.499 | ns |
| | Medium | 5.912 | 6.955 | 4.616 | 5.43 | 5.915 | 6.959 | 6.887 | 8.102 | 6.009 | 7.069 | ns |
| | Medium fast | 5.5 | 6.469 | 4.231 | 4.978 | 5.5 | 6.471 | 6.672 | 7.849 | 5.835 | 6.865 | ns |
| | Fast | 5.462 | 6.426 | 4.194 | 4.935 | 5.463 | 6.427 | 6.646 | 7.819 | 5.828 | 6.857 | ns |
| 4 mA | Slow | 6.109 | 7.186 | 4.708 | 5.539 | 6.098 | 7.174 | 8.005 | 9.418 | 7.033 | 8.274 | ns |
| | Medium | 5.355 | 6.299 | 4.034 | 4.746 | 5.338 | 6.28 | 7.637 | 8.985 | 6.672 | 7.849 | ns |
| | Medium fast | 4.953 | 5.826 | 3.685 | 4.336 | 4.932 | 5.802 | 7.44 | 8.752 | 6.499 | 7.646 | ns |
| | Fast | 4.911 | 5.777 | 3.658 | 4.303 | 4.89 | 5.754 | 7.427 | 8.737 | 6.488 | 7.632 | ns |
| 6 mA | Slow | 5.89 | 6.929 | 4.506 | 5.301 | 5.874 | 6.911 | 8.337 | 9.808 | 7.315 | 8.605 | ns |
| | Medium | 5.176 | 6.089 | 3.862 | 4.543 | 5.155 | 6.065 | 7.986 | 9.394 | 6.943 | 8.168 | ns |
| | Medium fast | 4.792 | 5.637 | 3.523 | 4.145 | 4.765 | 5.606 | 7.808 | 9.186 | 6.775 | 7.97 | ns |
| | Fast | 4.754 | 5.593 | 3.486 | 4.101 | 4.728 | 5.563 | 7.777 | 9.149 | 6.769 | 7.963 | ns |

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

Table 84 • LVCMOS 1.2 V Transmitter Characteristics for MSIO I/O Bank (Output and Tristate Buffers)

| Output Drive Selection | Slew Control | T_{DP} | | T_{ZL} | | T_{ZH} | | T_{HZ}^1 | | T_{LZ}^1 | | Unit |
|------------------------|--------------|----------|-------|----------|-------|----------|-------|------------|--------|------------|--------|------|
| | | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| 2 mA | Slow | 6.746 | 7.937 | 7.458 | 8.774 | 8.172 | 9.614 | 9.867 | 11.608 | 8.393 | 9.874 | ns |
| 4 mA | Slow | 7.068 | 8.315 | 6.678 | 7.857 | 7.474 | 8.793 | 10.986 | 12.924 | 9.043 | 10.638 | ns |

1. Delay increases with drive strength are inherent to built-in slew control circuitry for simultaneous switching output (SSO) management.

Table 95 • HSTL DC Output Voltage Specification Applicable to DDRIO I/O Bank Only

| Parameter | Symbol | Min | Max | Unit |
|---|----------------------|-----------------|-----|------|
| HSTL Class I | | | | |
| DC output logic high | V_{OH} | $V_{DDI} - 0.4$ | | V |
| DC output logic low | V_{OL} | | 0.4 | V |
| Output minimum source DC current (MSIO and DDRIO I/O banks) | I_{OH} at V_{OH} | -8.0 | | mA |
| Output minimum sink current (MSIO and DDRIO I/O banks) | I_{OL} at V_{OL} | 8.0 | | mA |
| HSTL Class II | | | | |
| DC output logic high | V_{OH} | $V_{DDI} - 0.4$ | | V |
| DC output logic low | V_{OL} | | 0.4 | V |
| Output minimum source DC current | I_{OH} at V_{OH} | -16.0 | | mA |
| Output minimum sink current | I_{OL} at V_{OL} | 16.0 | | mA |

Table 96 • HSTL DC Differential Voltage Specification

| Parameter | Symbol | Min | Unit |
|-------------------------------|---------------|-----|------|
| DC input differential voltage | V_{ID} (DC) | 0.2 | V |

Table 97 • HSTL AC Differential Voltage Specifications

| Parameter | Symbol | Min | Max | Unit |
|-------------------------------------|------------|------|-----|------|
| AC input differential voltage | V_{DIFF} | 0.4 | | V |
| AC differential cross point voltage | V_x | 0.68 | 0.9 | V |

Table 98 • HSTL Minimum and Maximum AC Switching Speed

| Parameter | Symbol | Max | Unit | Conditions |
|-------------------|-----------|-----|------|--------------------------------------|
| Maximum data rate | D_{MAX} | 400 | Mbps | AC loading: per JEDEC specifications |

Table 99 • HSTL Impedance Specification

| Parameter | Symbol | Typ | Unit | Conditions |
|---|-----------|------------|----------|-------------------------------------|
| Supported output driver calibrated impedance (for DDRIO I/O bank) | R_{REF} | 25.5, 47.8 | Ω | Reference resistance = 191 Ω |
| Effective impedance value (ODT for DDRIO I/O bank only) | R_{TT} | 47.8 | Ω | Reference resistance = 191 Ω |

Table 136 • SSTL15 AC Test Parameter Specifications (for DDRIO I/O Bank Only)

| Parameter | Symbol | Typ | Unit |
|--|----------------|------|----------|
| Measuring/trip point for data path | V_{TRIP} | 0.75 | V |
| Resistance for enable path (T_{ZH} , T_{ZL} , T_{HZ} , T_{LZ}) | R_{ENT} | 2K | Ω |
| Capacitive loading for enable path (T_{ZH} , T_{ZL} , T_{HZ} , T_{LZ}) | C_{ENT} | 5 | pF |
| Reference resistance for data test path for SSTL15 Class I (T_{DP}) | R_{TT_TEST} | 50 | Ω |
| Reference resistance for data test path for SSTL15 Class II (T_{DP}) | R_{TT_TEST} | 25 | Ω |
| Capacitive loading for data path (T_{DP}) | C_{LOAD} | 5 | pF |

AC Switching Characteristics

Worst commercial-case conditions: $T_J = 85\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$, $V_{DDI} = 1.425\text{ V}$

Table 137 • DDR3/SSTL15 Receiver Characteristics for DDRIO I/O Bank – with Calibration Only

| | On-Die Termination (ODT) | T_{PY} | | Unit |
|---------------------|--------------------------|----------|-------|------|
| | | -1 | -Std | |
| Pseudo differential | None | 1.605 | 1.888 | ns |
| | 20 | 1.616 | 1.901 | ns |
| | 30 | 1.613 | 1.897 | ns |
| | 40 | 1.611 | 1.895 | ns |
| | 60 | 1.609 | 1.893 | ns |
| | 120 | 1.607 | 1.89 | ns |
| True differential | None | 1.623 | 1.91 | ns |
| | 20 | 1.637 | 1.926 | ns |
| | 30 | 1.63 | 1.918 | ns |
| | 40 | 1.626 | 1.914 | ns |
| | 60 | 1.622 | 1.91 | ns |
| | 120 | 1.619 | 1.905 | ns |

Table 138 • DDR3/SSTL15 Transmitter Characteristics (Output and Tristate Buffers)

| | T_{DP} | | T_{ZL} | | T_{ZH} | | T_{HZ} | | T_{LZ} | | Unit |
|---|----------|-------|----------|-------|----------|-------|----------|-------|----------|-------|------|
| | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| DDR3 Reduced Drive/SSTL15 Class I (for DDRIO I/O Bank) | | | | | | | | | | | |
| Single-ended | 2.533 | 2.98 | 2.522 | 2.967 | 2.523 | 2.968 | 2.427 | 2.855 | 2.428 | 2.856 | ns |
| Differential | 2.555 | 3.005 | 3.073 | 3.615 | 3.073 | 3.615 | 2.416 | 2.843 | 2.416 | 2.843 | ns |
| DDR3 Full Drive/SSTL15 Class II (for DDRIO I/O Bank) | | | | | | | | | | | |
| Single-ended | 2.53 | 2.977 | 2.514 | 2.958 | 2.516 | 2.96 | 2.422 | 2.849 | 2.425 | 2.852 | ns |
| Differential | 2.552 | 3.002 | 2.591 | 3.048 | 2.59 | 3.047 | 2.882 | 3.391 | 2.881 | 3.39 | ns |

Table 150 • LPDDR Full Drive for DDRIO I/O Bank (Output and Tristate Buffers)

| | T_{DP} | | T_{ENZL} | | T_{ENZH} | | T_{ENHZ} | | T_{ENLZ} | | Unit |
|--------------|----------|-------|------------|-------|------------|-------|------------|-------|------------|-------|------|
| | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | -1 | -Std | |
| Single-ended | 2.281 | 2.683 | 2.196 | 2.584 | 2.195 | 2.583 | 2.171 | 2.555 | 2.17 | 2.554 | ns |
| Differential | 2.298 | 2.703 | 2.288 | 2.692 | 2.288 | 2.692 | 2.593 | 3.051 | 2.593 | 3.051 | ns |

Minimum and Maximum DC/AC Input and Output Levels Specification using LPDDR-LVCMOS 1.8 V Mode

Table 151 • LPDDR-LVCMOS 1.8 V Mode Recommended DC Operating Conditions

| Parameter | Symbol | Min | Typ | Max | Unit |
|----------------|-----------|-------|-----|------|------|
| Supply voltage | V_{DDI} | 1.710 | 1.8 | 1.89 | V |

Table 152 • LPDDR-LVCMOS 1.8 V Mode DC Input Voltage Specification

| Parameter | Symbol | Min | Max | Unit |
|---|---------------|-----------------------|-----------------------|------|
| DC input logic high (for MSIOD and DDRIO I/O banks) | V_{IH} (DC) | $0.65 \times V_{DDI}$ | 1.89 | V |
| DC input logic high (for MSIO I/O bank) | V_{IH} (DC) | $0.65 \times V_{DDI}$ | 3.45 | V |
| DC input logic low | V_{IL} (DC) | -0.3 | $0.35 \times V_{DDI}$ | V |
| Input current high ¹ | I_{IH} (DC) | | | |
| Input current low ¹ | I_{IL} (DC) | | | |

1. See Table 24, page 22.

Table 153 • LPDDR-LVCMOS 1.8 V Mode DC Output Voltage Specification

| Parameter | Symbol | Min | Max | Unit |
|----------------------|----------|------------------|------|------|
| DC output logic high | V_{OH} | $V_{DDI} - 0.45$ | | V |
| DC output logic low | V_{OL} | | 0.45 | V |

Table 154 • LPDDR-LVCMOS 1.8 V Minimum and Maximum AC Switching Speeds

| Parameter | Symbol | Max | Unit | Conditions |
|--|-----------|-----|------|--|
| Maximum data rate (for DDRIO I/O bank) | D_{MAX} | 400 | Mbps | AC loading: 17pf load, 8 ma drive and above/all slew |

Table 155 • LPDDR-LVCMOS 1.8 V Calibrated Impedance Option

| Parameter | Symbol | Typ | Unit |
|---|----------|------------------------|----------|
| Supported output driver calibrated impedance (for DDRIO I/O bank) | RODT_CAL | 75, 60, 50, 33, 25, 20 | Ω |

Table 215 • LVPECL DC Input Voltage Specification

| Parameter | Symbol | Min | Max | Unit |
|------------------|--------|-----|------|------|
| DC input voltage | V_I | 0 | 3.45 | V |

Table 216 • LVPECL DC Differential Voltage Specification

| Parameter | Symbol | Min | Typ | Max | Unit |
|----------------------------|-------------|-----|-----|-------|------|
| Input common mode voltage | V_{ICM} | 0.3 | | 2.8 | V |
| Input differential voltage | V_{IDIFF} | 100 | 300 | 1,000 | mV |

Table 217 • LVPECL Minimum and Maximum AC Switching Speeds

| Parameter | Symbol | Max | Unit |
|-------------------|-----------|-----|------|
| Maximum data rate | D_{MAX} | 900 | Mbps |

AC Switching Characteristics

Worst commercial-case conditions: $T_J = 85\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$, $V_{DDI} = 2.375\text{ V}$.

Table 218 • LVPECL Receiver Characteristics for MSIO I/O Bank

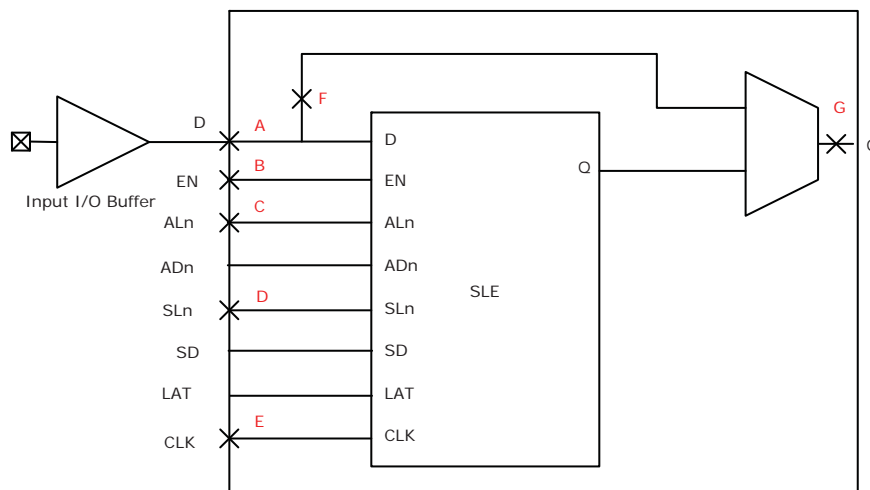
| On-Die Termination (ODT) | T_{PY} | | Unit |
|--------------------------|----------|-------|------|
| | -1 | -Std | |
| None | 2.572 | 3.025 | ns |
| 100 | 2.569 | 3.023 | ns |

2.3.8 I/O Register Specifications

This section describes input and output register specifications.

2.3.8.1 Input Register

Figure 6 • Timing Model for Input Register

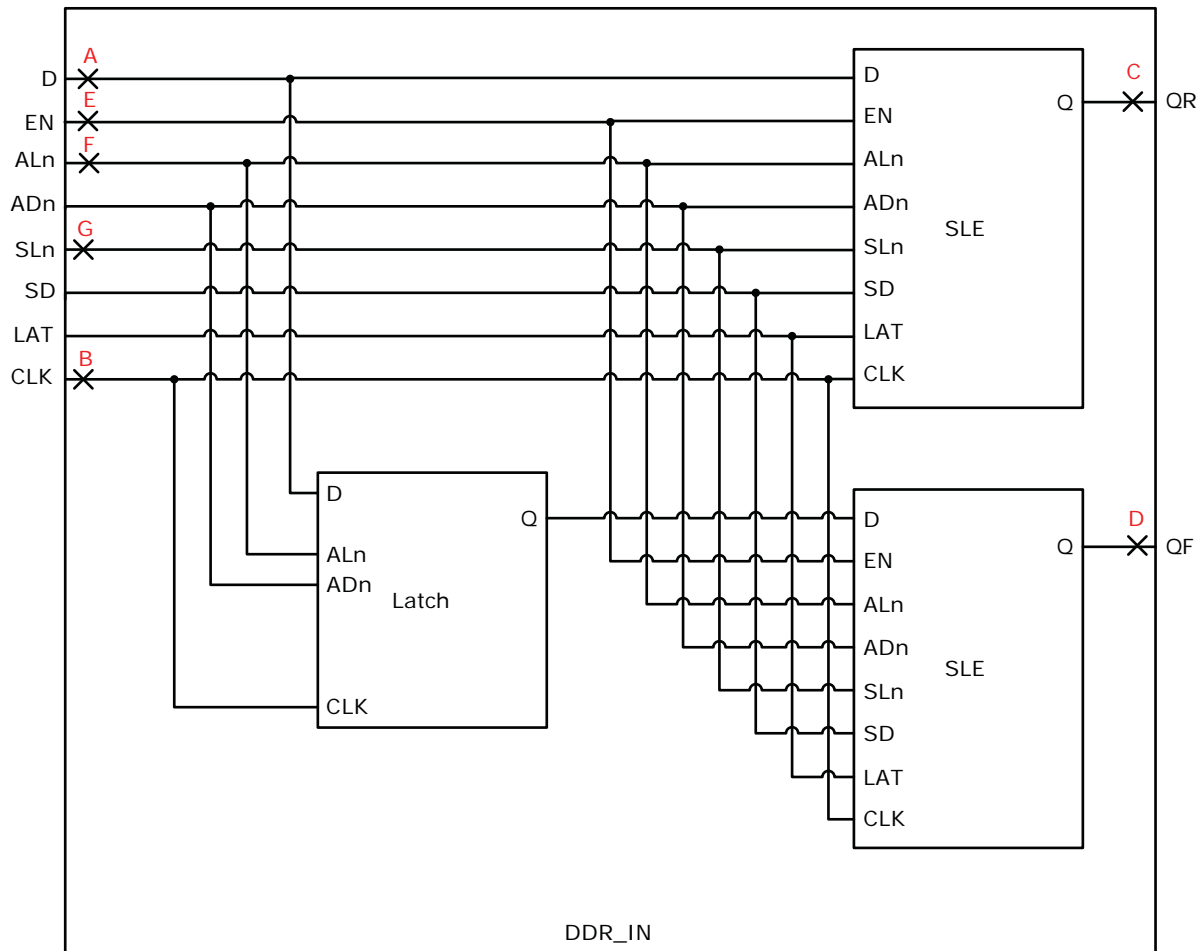


2.3.9 DDR Module Specification

This section describes input and output DDR module and timing specifications.

2.3.9.1 Input DDR Module

Figure 10 • Input DDR Module



2.3.12.2 FPGA Fabric Micro SRAM (μ SRAM)

The following table lists the μ SRAM in 64×18 mode in worst commercial-case conditions when $T_J = 85^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 237 • μ SRAM (RAM64x18) in 64×18 Mode

| Parameter | Symbol | -1 | | -Std | | Unit |
|---|-----------------|--------|--------|--------|--------|-------|
| | | Min | Max | Min | Max | |
| Read clock period | T_{CY} | 4 | | 4 | | ns |
| Read clock minimum pulse width high | $T_{CLKMPWH}$ | 1.8 | | 1.8 | | ns |
| Read clock minimum pulse width low | $T_{CLKMPWL}$ | 1.8 | | 1.8 | | ns |
| Read pipeline clock period | T_{PLCY} | 4 | | 4 | | ns |
| Read pipeline clock minimum pulse width high | $T_{PLCLKMPWH}$ | 1.8 | | 1.8 | | ns |
| Read pipeline clock minimum pulse width low | $T_{PLCLKMPWL}$ | 1.8 | | 1.8 | | ns |
| Read access time with pipeline register | T_{CLK2Q} | | 0.266 | | 0.313 | ns |
| Read access time without pipeline register | | | | 1.677 | | 1.973 |
| Read address setup time in synchronous mode | T_{ADDRSU} | 0.301 | | 0.354 | | ns |
| Read address setup time in asynchronous mode | | | 1.856 | | 2.184 | |
| Read address hold time in synchronous mode | T_{ADDRHD} | 0.091 | | 0.107 | | ns |
| Read address hold time in asynchronous mode | | | -0.778 | | -0.915 | |
| Read enable setup time | T_{RDENSU} | 0.278 | | 0.327 | | ns |
| Read enable hold time | T_{RDENHD} | 0.057 | | 0.067 | | ns |
| Read block select setup time | T_{BLKSU} | 1.839 | | 2.163 | | ns |
| Read block select hold time | T_{BLKHD} | -0.65 | | -0.765 | | ns |
| Read block select to out disable time (when pipelined register is disabled) | T_{BLK2Q} | | 2.036 | | 2.396 | ns |
| Read asynchronous reset removal time (pipelined clock) | T_{RSTREM} | -0.023 | | -0.027 | | ns |
| Read asynchronous reset removal time (non-pipelined clock) | | | 0.046 | | 0.054 | |
| Read asynchronous reset recovery time (pipelined clock) | T_{RSTREC} | 0.507 | | 0.597 | | ns |
| Read asynchronous reset recovery time (non-pipelined clock) | | | 0.236 | | 0.278 | |
| Read asynchronous reset to output propagation delay (with pipelined register enabled) | T_{R2Q} | | 0.839 | | 0.987 | ns |
| Read synchronous reset setup time | T_{SRSTSU} | 0.271 | | 0.319 | | ns |
| Read synchronous reset hold time | T_{SRSTHD} | 0.061 | | 0.071 | | ns |
| Write clock period | T_{CCY} | 4 | | 4 | | ns |
| Write clock minimum pulse width high | $T_{CCLKMPWH}$ | 1.8 | | 1.8 | | ns |
| Write clock minimum pulse width low | $T_{CCLKMPWL}$ | 1.8 | | 1.8 | | ns |
| Write block setup time | T_{BLKCSU} | 0.404 | | 0.476 | | ns |
| Write block hold time | T_{BLKCHD} | 0.007 | | 0.008 | | ns |
| Write input data setup time | T_{DINCSU} | 0.115 | | 0.135 | | ns |
| Write input data hold time | T_{DINCHD} | 0.15 | | 0.177 | | ns |

2.3.14 Math Block Timing Characteristics

The fundamental building block in any digital signal processing algorithm is the multiply-accumulate function. Each IGLOO2 and SmartFusion2 SoC math block supports 18×18 signed multiplication, dot product, and built-in addition, subtraction, and accumulation units to combine multiplication results efficiently. The following table lists the math blocks with all registers used in worst commercial-case conditions when $T_J = 85\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 268 • Math Blocks with all Registers Used

| Parameter | Symbol | -1 | | -Std | | Unit |
|-------------------------------------|-----------------|--------|-------|--------|-------|------|
| | | Min | Max | Min | Max | |
| Input, control register setup time | T_{MISU} | 0.149 | | 0.176 | | ns |
| Input, control register hold time | T_{MIHD} | 1.68 | | 1.976 | | ns |
| CDIN input setup time | $T_{MOCDINSU}$ | 0.185 | | 0.218 | | ns |
| CDIN input hold time | $T_{MOCDINHHD}$ | 0.08 | | 0.094 | | ns |
| Synchronous reset/enable setup time | $T_{MSRSTENSU}$ | -0.419 | | -0.493 | | ns |
| Synchronous reset/enable hold time | $T_{MSRSTENHD}$ | 0.011 | | 0.013 | | ns |
| Asynchronous reset removal time | $T_{MARSTREM}$ | 0 | | 0 | | ns |
| Asynchronous reset recovery time | $T_{MARSTREC}$ | 0.088 | | 0.104 | | ns |
| Output register clock to out delay | T_{MOCQ} | | 0.232 | | 0.273 | ns |
| CLK minimum period | T_{MCLKMP} | 2.245 | | 2.641 | | ns |

The following table lists the math blocks with input bypassed and output registers used in worst commercial-case conditions when $T_J = 85\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 269 • Math Block with Input Bypassed and Output Registers Used

| Parameter | Symbol | -1 | | -Std | | Unit |
|-------------------------------------|-----------------|--------|-------|--------|-------|------|
| | | Min | Max | Min | Max | |
| Output register setup time | T_{MOSU} | 2.294 | | 2.699 | | ns |
| Output register hold time | T_{MOHD} | 1.68 | | 1.976 | | ns |
| CDIN input setup time | $T_{MOCDINSU}$ | 0.115 | | 0.136 | | ns |
| CDIN input hold time | $T_{MOCDINHHD}$ | -0.444 | | -0.522 | | ns |
| Synchronous reset/enable setup time | $T_{MSRSTENSU}$ | -0.419 | | -0.493 | | ns |
| Synchronous reset/enable hold time | $T_{MSRSTENHD}$ | 0.011 | | 0.013 | | ns |
| Asynchronous reset removal time | $T_{MARSTREM}$ | 0 | | 0 | | ns |
| Asynchronous reset recovery time | $T_{MARSTREC}$ | 0.014 | | 0.017 | | ns |
| Output register clock to out delay | T_{MOCQ} | | 0.232 | | 0.273 | ns |
| CLK minimum period | T_{MCLKMP} | 2.179 | | 2.563 | | ns |

1. The minimum output clock frequency is limited by the PLL. For more information, see [UG0449: SmartFusion2 and IGLOO2 Clocking Resources User Guide](#).
2. The PLL is used in conjunction with the Clock Conditioning Circuitry. Performance is limited by the CCC output frequency.

The following table lists the CCC/PLL jitter specifications in worst-case industrial conditions when $T_J = 100\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 283 • IGLOO2 and SmartFusion2 SoC FPGAs CCC/PLL Jitter Specifications

| CCC Output Maximum Peak-to-Peak Period Jitter F_{OUT_CCC} | | | | | | |
|--|--|--|--------------|--|---------------|----|
| Parameter | Conditions/Package Combinations | | | | Unit | |
| 10 FG484, 050 FG896/FG484/FCS325 Packages¹ | SSO = 0 | $0 < SSO \leq 2$ | $SSO \leq 4$ | $SSO \leq 8$ | $SSO \leq 16$ | |
| 20 MHz to 100 MHz | $\text{Max}(110, \pm 1\% \times (1/F_{OUT_CCC}))$ | $\text{Max}(150, \pm 1\% \times (1/F_{OUT_CCC}))$ | | | | ps |
| 100 MHz to 400 MHz | $\text{Max}(120, \pm 1\% \times (1/F_{OUT_CCC}))$ | $\text{Max}(150, \pm 1\% \times (1/F_{OUT_CCC}))$ | | $\text{Max}(170, \pm 1\% \times (1/F_{OUT_CCC}))$ | | ps |
| 025 FG484/FCS325 Package¹ | $0 < SSO \leq 16$ | | | | | |
| 20 MHz to 74 MHz | $\pm 1\% \times (1/F_{OUT_CCC})$ | | | | | ps |
| 74 MHz to 400 MHz | 210 | | | | | ps |
| 005 FG484 Package¹ | $0 < SSO \leq 16$ | | | | | |
| 20 MHz to 53 MHz | $\pm 1\% \times (1/F_{OUT_CCC})$ | | | | | ps |
| 53 MHz to 400 MHz | 270 | | | | | ps |
| 090 FG676 and FC325 Package¹ | $0 < SSO \leq 16$ | | | | | |
| 20 MHz to 100 MHz | $\pm 1\% \times (1/F_{OUT_CCC})$ | | | | | ps |
| 100 MHz to 400 MHz | 150 | | | | | ps |
| 060 FG676 Package¹ | $0 < SSO \leq 16$ | | | | | |
| 20 MHz to 100 MHz | $\pm 1\% \times (1/F_{OUT_CCC})$ | | | | | ps |
| 100 MHz to 400 MHz | 150 | | | | | ps |
| 150 FC1152 Package¹ | $0 < SSO \leq 16$ | | | | | |
| 20 MHz to 100 MHz | $\pm 1\% \times (1/F_{OUT_CCC})$ | | | | | ps |
| 100 MHz to 400 MHz | 120 | | | | | ps |

1. SSO data is based on LVCMOS 2.5 V MSIO and/or MSIOD bank I/Os.

The following table lists the IGLOO2 DEVRST_N to functional times in worst-case industrial conditions when $T_J = 100\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 292 • DEVRST_N to Functional Times for IGLOO2

| Symbol | From | To | Description | Maximum Power-up to Functional Time for IGLOO2 (uS) | | | | | | |
|------------------|------------------|-------------------------|---|---|-----|-----|-----|-----|-----|-----|
| | | | | 005 | 010 | 025 | 050 | 060 | 090 | 150 |
| $T_{POR2OUT}$ | POWER_ON_RESET_N | Output available at I/O | Fabric to output | 114 | 116 | 113 | 113 | 115 | 115 | 114 |
| $T_{DEVRST2OUT}$ | DEVRST_N | Output available at I/O | V_{DD} at its minimum threshold level to output | 314 | 353 | 314 | 307 | 343 | 341 | 341 |
| $T_{DEVRST2POR}$ | DEVRST_N | POWER_ON_RESET_N | V_{DD} at its minimum threshold level to fabric | 200 | 238 | 201 | 195 | 230 | 229 | 227 |
| $T_{DEVRST2WPU}$ | DEVRST_N | DDRIO Inbuf weak pull | DEVRST_N to Inbuf weak pull | 208 | 202 | 197 | 193 | 216 | 215 | 215 |
| | DEVRST_N | MSIO Inbuf weak pull | DEVRST_N to Inbuf weak pull | 208 | 202 | 197 | 193 | 216 | 215 | 215 |
| | DEVRST_N | MSIOD Inbuf weak pull | DEVRST_N to Inbuf weak pull | 208 | 202 | 197 | 193 | 216 | 215 | 215 |

Table 293 • Flash*Freeze Entry and Exit Times (continued)

| Parameter | Symbol | Entry/Exit Timing FCLK = 100MHz | | | Entry/Exit Timing FCLK = 3 MHz | |
|--|----------|--|-----|-------------|-----------------------------------|--|
| | | 005, 010, 025, 060, 090, and 150 | 050 | All Devices | Unit | Conditions |
| Exit time with respect to the fabric PLL lock ¹ | TFF_EXIT | 1.5 | 1.5 | 1.5 | ms | eNVM and MSS/HPMS PLL = ON during F*F |
| | | 1.5 | 1.5 | 1.5 | ms | eNVM and MSS/HPMS PLL = OFF during F*F and both are turned back on at exit |
| Exit time with respect to the fabric buffer output | TFF_EXIT | 21 | 15 | 21 | µs | eNVM and MSS/HPMS PLL = ON during F*F |
| | | 65 | 55 | 65 | µs | eNVM and MSS/HPMS PLL = OFF during F*F and both are turned back on at exit |

1. PLL Lock Delay set to 1024 cycles (default).

2.3.28 DDR Memory Interface Characteristics

The following table lists the DDR memory interface characteristics in worst-case industrial conditions when $T_J = 100\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 294 • DDR Memory Interface Characteristics

| Standard | Supported Data Rate | | Unit |
|----------|---------------------|-----|------|
| | Min | Max | |
| DDR3 | 667 | 667 | Mbps |
| DDR2 | 667 | 667 | Mbps |
| LPDDR | 50 | 400 | Mbps |

2.3.29 SFP Transceiver Characteristics

IGLOO2 and SmartFusion2 SerDes complies with small form-factor pluggable (SFP) requirements as specified in SFP INF-80741. The following table provides the electrical characteristics.

The following table lists the SFP transceiver electrical characteristics in worst-case industrial conditions when $T_J = 100\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 295 • SFP Transceiver Electrical Characteristics

| Pin | Direction | Differential Peak-Peak Voltage | | Unit |
|--------------------|-----------|--------------------------------|------|------|
| | | Min | Max | |
| RD+/- ¹ | Output | 1600 | 2400 | mV |
| TD+/- ² | Input | 350 | 2400 | mV |

1. Based on default SerDes transmitter settings for PCIe Gen1. Lower amplitudes are available through programming changes to TX_AMP setting.
2. Based on Input Voltage Common-Mode (VICM) = 0 V. Requires AC Coupling.

2.3.30 SerDes Electrical and Timing AC and DC Characteristics

PCIe is a high-speed, packet-based, point-to-point, low-pin-count, serial interconnect bus. The IGLOO2 and SmartFusion2 SoC FPGAs has up to four hard high-speed serial interface blocks. Each SerDes block contains a PCIe system block. The PCIe system is connected to the SerDes block.

The following table lists the transmitter parameters in worst-case industrial conditions when $T_J = 100\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 296 • Transmitter Parameters

| Symbol | Description | Min | Max | Unit |
|---------------|--|-------|---------------|---------------|
| VTX-DIFF-PP | Differential swing (2.5 Gbps, 5.0 Gbps) | 0.8 | 1.2 | V |
| VTX-CM-AC-P | Output common mode voltage (2.5 Gbps) | | 20 | mV |
| VTX-CM-AC-PP | Output common mode voltage (5.0 Gbps) | | 100 | mV |
| VTX-RISE-FALL | Rise and fall time (20% to 80%, 2.5 Gbps) | 0.125 | | UI |
| | Rise and fall time (20% to 80%, 5.0 Gbps) | 0.15 | | UI |
| ZTX-DIFF-DC | Output impedance–differential | 80 | 120 | Ω |
| LTX-SKEW | Lane-to-lane TX skew within a SerDes block (2.5 Gbps) | | 500 ps + 2 UI | ps |
| | Lane-to-lane TX skew within a SerDes block (5.0 Gbps) | | 500 ps + 4 UI | ps |
| RLTX-DIFF | Return loss differential mode (2.5 Gbps) | –10 | | dB |
| | Return loss differential mode (5.0 Gbps) 0.05 GHz to 1.25 GHz | –10 | | dB |
| | 1.25 GHz to 2.5 GHz | –8 | | dB |
| RLTX-CM | Return loss common mode (2.5 Gbps, 5.0 Gbps) | –6 | | dB |
| TX-LOCK-RST | Transmit PLL lock time from reset | | 10 | μs |
| VTX-AMP | 100 mV setting | 90 | 150 | mV |
| | 400 mV setting | 320 | 480 | mV |
| | 800 mV setting | 660 | 940 | mV |
| | 1200 mV setting | 950 | 1400 | mV |

The following table lists the receiver pa in worst-case industrial conditions when $T_J = 100\text{ }^\circ\text{C}$, $V_{DD} = 1.14\text{ V}$.

Table 297 • Receiver Parameters

| Symbol | Description | Min | Typ | Max | Unit |
|----------------------|---|-------|-------|-------|---------------|
| VRX-IN-PP-CC | Differential input peak-to-peak sensitivity (2.5 Gbps) | 0.238 | | 1.2 | V |
| | Differential input peak-to-peak sensitivity (2.5 Gbps, de-emphasized) | 0.219 | | 1.2 | V |
| | Differential input peak-to-peak sensitivity (5.0 Gbps) | 0.300 | | 1.2 | V |
| | Differential input peak-to-peak sensitivity (5.0 Gbps, de-emphasized) | 0.300 | | 1.2 | V |
| VRX-CM-AC-P | Input common mode range (AC coupled) | | | 150 | mV |
| ZRX-DIFF-DC | Differential input termination | 80 | 100 | 120 | Ω |
| REXT | External calibration resistor | 1,188 | 1,200 | 1,212 | Ω |
| CDR-LOCK-RST | CDR relock time from reset | | | 15 | μs |
| RLRX-DIFF | Return loss differential mode (2.5 Gbps) | -10 | | | dB |
| | Return loss differential mode (5.0 Gbps) | | | | |
| | 0.05 GHz to 1.25 GHz | -10 | | | dB |
| | 1.25 GHz to 2.5 GHz | -8 | | | dB |
| RLRX-CM | Return loss common mode (2.5 Gbps, 5.0 Gbps) | -6 | | | dB |
| RX-CID ¹ | CID limit PCIe Gen1/2 | | | 200 | UI |
| VRX-IDLE-DET-DIFF-PP | Signal detect limit | 65 | | 175 | mV |

1. AC-coupled, BER = e^{-12} , using synchronous clock.

Table 298 • SerDes Protocol Compliance

| Protocol | Maximum Data Rate (Gbps) | -1 | -Std |
|--------------|--------------------------|-----|------|
| PCIe Gen 1 | 2.5 | Yes | Yes |
| PCIe Gen 2 | 5.0 | Yes | |
| XAUI | 3.125 | Yes | |
| Generic EPCS | 3.2 | Yes | |
| Generic EPCS | 2.5 | Yes | Yes |